

# Silicon Carbide (SiC) Schottky Diode – EliteSiC, 4 A, 650 V, D1, D2PAK-2L

## FFSB0465A

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

### Features

- Max Junction Temperature 175°C
- Avalanche Rated 25 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
- This Device is Pb-Free, Halogen Free/BFR Free and RoHS Compliant

### Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits

### ABSOLUTE MAXIMUM RATINGS

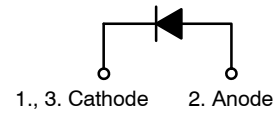
( $T_C = 25^\circ\text{C}$ , unless otherwise specified)

Symbol	Parameter	Rating	Unit	
$V_{RRM}$	Peak Repetitive Reverse Voltage	650	V	
$E_{AS}$	Single Pulse Avalanche Energy (Note 1)	25	mJ	
$I_F$	Continuous Rectified Forward Current @ $T_C < 160^\circ\text{C}$	4	A	
	Continuous Rectified Forward Current @ $T_C < 135^\circ\text{C}$	7.7		
$I_{F, Max}$	Non-Repetitive Peak Forward Surge Current	$T_C = 25^\circ\text{C}$ , 10 $\mu\text{s}$	A	
		$T_C = 150^\circ\text{C}$ , 10 $\mu\text{s}$		330
$I_{F, SM}$	Non-Repetitive Forward Surge Current	Half-Sine Pulse, $t_p = 8.3$ ms	38	A
$I_{F, RM}$	Repetitive Forward Surge Current	Half-Sine Pulse, $t_p = 8.3$ ms	18	A
$P_{tot}$	Power Dissipation	$T_C = 25^\circ\text{C}$	63	W
		$T_C = 150^\circ\text{C}$		
$T_J, T_{STG}$	Operating and Storage Temperature Range	-55 to +175	$^\circ\text{C}$	

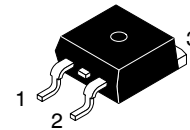
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1.  $E_{AS}$  of 25 mJ is based on starting  $T_J = 25^\circ\text{C}$ ,  $L = 0.5$  mH,  $I_{AS} = 10$  A,  $V = 50$  V.

### ELECTRICAL CONNECTION

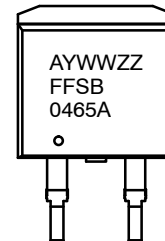


Schottky Diode



D<sup>2</sup>PAK2 (TO-263-2L)  
CASE 418BK

### MARKING DIAGRAM



- A = Assembly Plant Code
- YWW = Date Code (Year & Week)
- ZZ = Lot Code
- FFSB0465A = Specific Device Code

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

# FFSB0465A

## THERMAL CHARACTERISTICS

Symbol	Parameter	Ratings	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	2.38	$^{\circ}\text{C}/\text{W}$

## ELECTRICAL CHARACTERISTICS ( $T_C = 25^{\circ}\text{C}$ , unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_F$	Forward Voltage	$I_F = 4\text{ A}, T_C = 25^{\circ}\text{C}$	-	1.50	1.75	V
		$I_F = 4\text{ A}, T_C = 125^{\circ}\text{C}$	-	1.6	2.0	
		$I_F = 4\text{ A}, T_C = 175^{\circ}\text{C}$	-	1.72	2.4	
$I_R$	Reverse Current	$V_R = 650\text{ V}, T_C = 25^{\circ}\text{C}$	-	-	200	$\mu\text{A}$
		$V_R = 650\text{ V}, T_C = 125^{\circ}\text{C}$	-	-	400	
		$V_R = 650\text{ V}, T_C = 175^{\circ}\text{C}$	-	-	600	
$Q_C$	Total Capacitive Charge	$V = 400\text{ V}$	-	16	-	nC
C	Total Capacitance	$V_R = 1\text{ V}, f = 100\text{ kHz}$	-	258	-	pF
		$V_R = 200\text{ V}, f = 100\text{ kHz}$	-	29	-	
		$V_R = 400\text{ V}, f = 100\text{ kHz}$	-	21	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Mark	Package	Packing Method <sup>†</sup>	Reel Size	Tape Width	Quantity
FFSB0465A	FFSB0465A	D2PAK-2L	Tape/Reel	N/A	N/A	800 Units

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

TYPICAL CHARACTERISTICS  $T_J = 25^\circ\text{C}$  UNLESS OTHERWISE NOTED

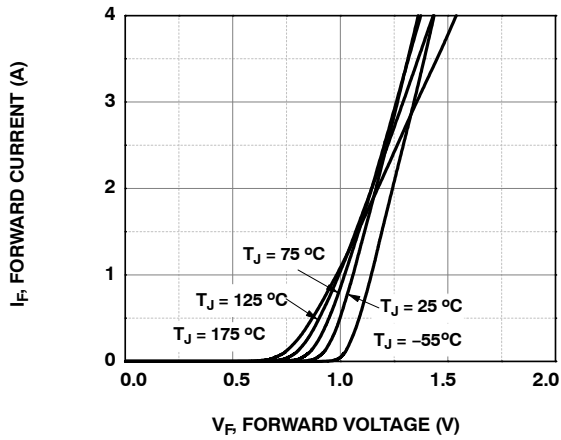


Figure 1. Forward Characteristics

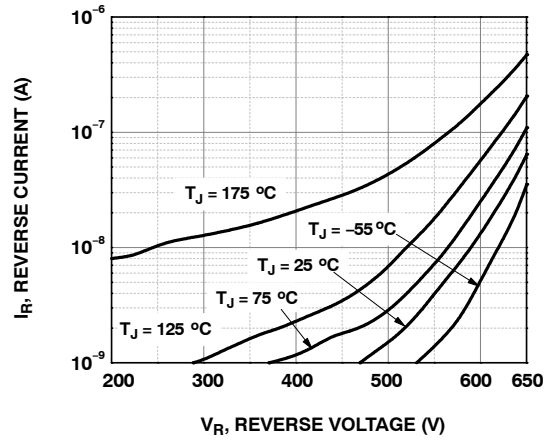


Figure 2. Reverse Characteristics

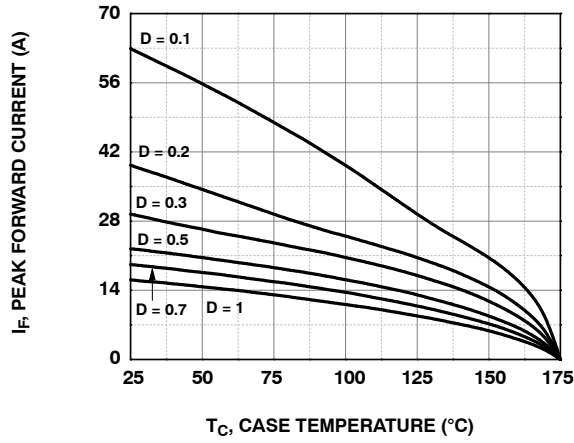


Figure 3. Current Derating

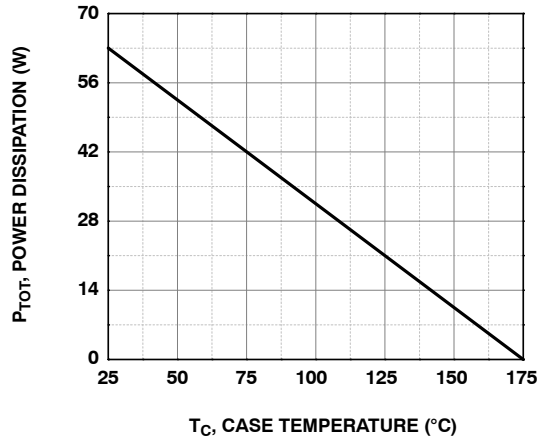


Figure 4. Power Derating

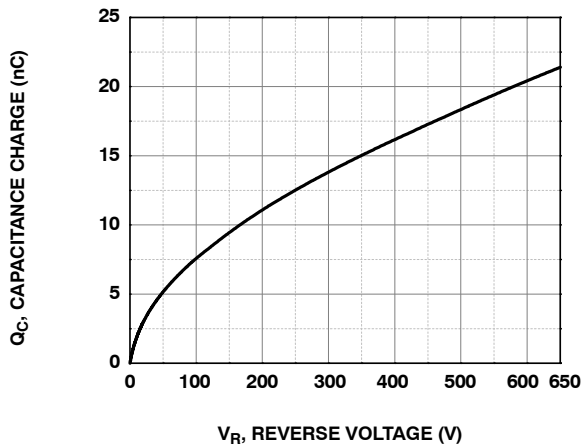


Figure 5. Capacitance Charge vs. Reverse Voltage

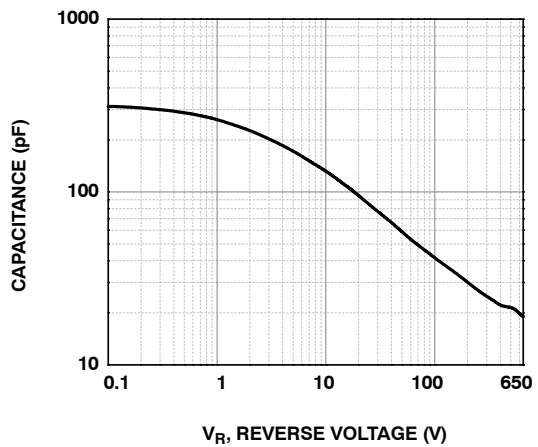


Figure 6. Capacitance vs. Reverse Voltage

TYPICAL CHARACTERISTICS  $T_J = 25^\circ\text{C}$  UNLESS OTHERWISE NOTED (CONTINUED)

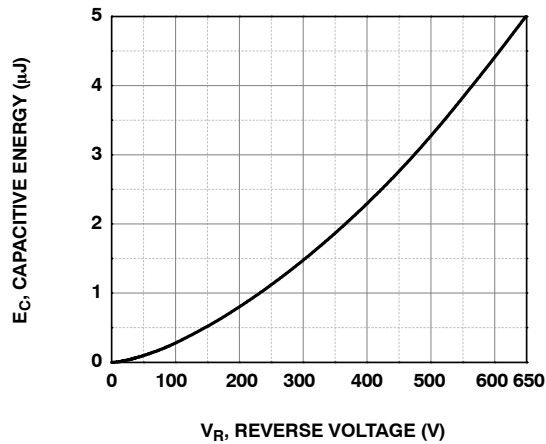


Figure 7. Capacitance Stored Energy

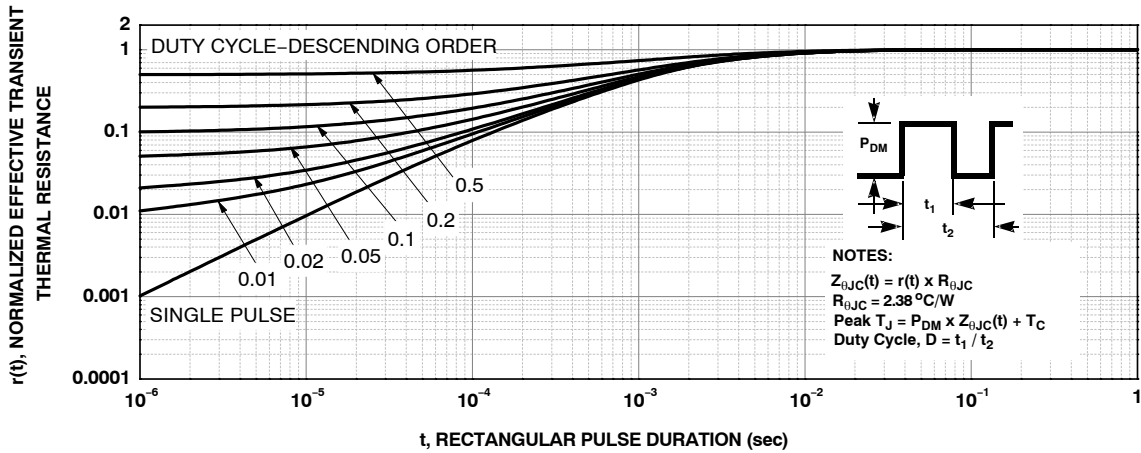


Figure 8. Junction-to-Case Transient Thermal Response Curve

TEST CIRCUIT AND WAVEFORMS

L = 0.5 mH  
 R < 0.1Ω  
 V<sub>DD</sub> = 50V  
 $E_{AVL} = 1/2LI^2 [V_{R(AVL)} / (V_{R(AVL)} - V_{DD})]$   
 Q1 = IGBT (BV<sub>CES</sub> > DUT V<sub>R(AVL)</sub>)

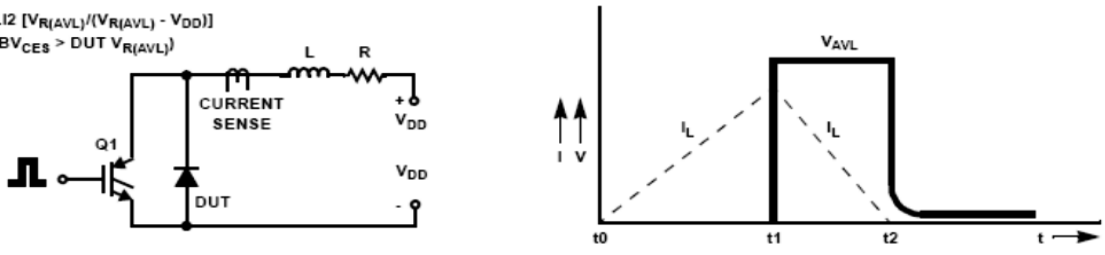


Figure 9. Unclamped Inductive Switching Test Circuit & Waveform

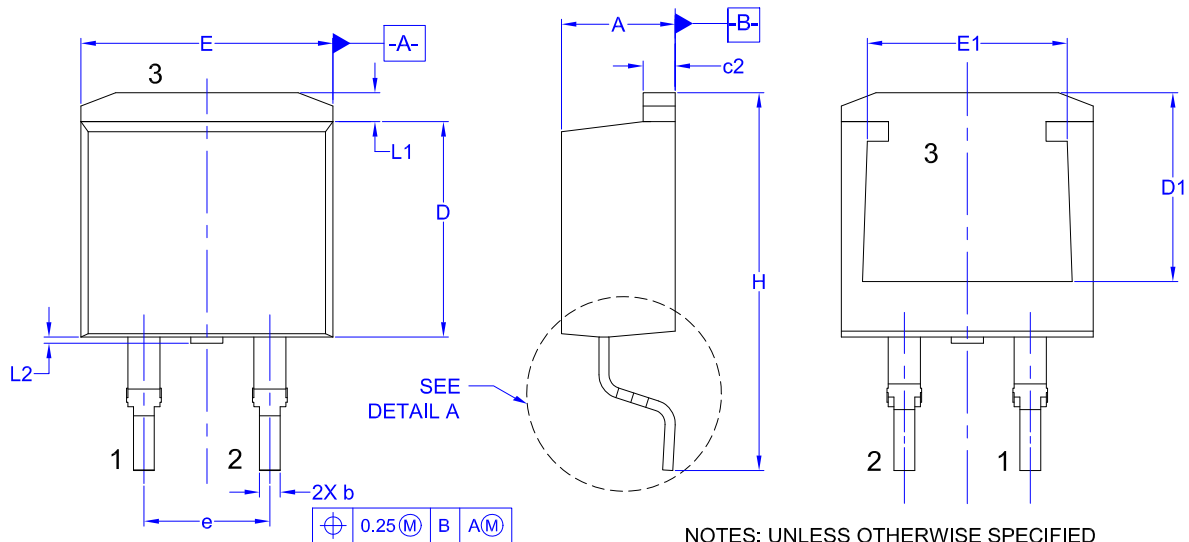
# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS



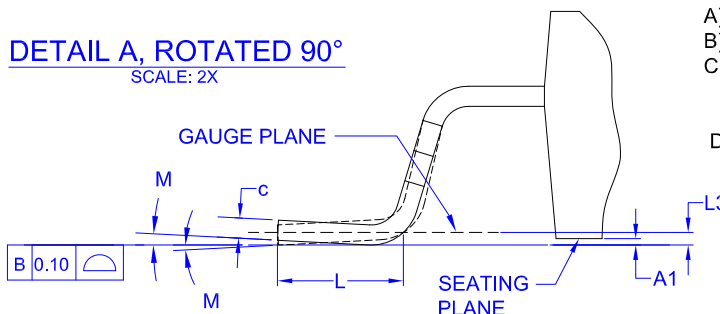
**D<sup>2</sup>PAK2 (TO-263-2L)**  
**CASE 418BK**  
**ISSUE O**

DATE 02 AUG 2018

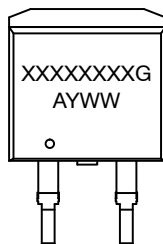


NOTES: UNLESS OTHERWISE SPECIFIED  
 A) ALL DIMENSIONS ARE IN MILLIMETERS.  
 B) REFERENCE JEDEC, TO-263, VARIATION AB.  
 C) DIMENSIONING AND TOLERANCING PER DIMENSIONING AND TOLERANCING PER ASME Y14.5 - 2009.  
 D) LANDPATTERN RECOMMENDATION PER IPC TO254P1524X482-3N

**DETAIL A, ROTATED 90°**  
 SCALE: 2X

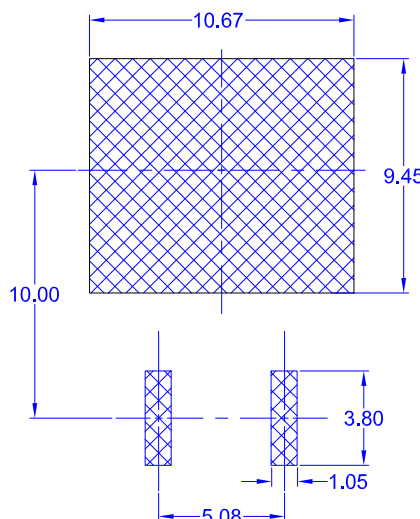


**GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code  
 A = Assembly Location  
 Y = Year  
 WW = Work Week  
 G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.



**LAND PATTERN RECOMMENDATION**  
 UNLESS NOTED, ALL DIMS TYPICAL

DIM	MILLIMETERS		
	MIN	NOM	MAX
A	4.06	4.57	4.83
A1	0.00	0.10	0.25
b	0.51	0.81	0.99
c	0.30	0.407	0.74
c2	1.14	1.30	1.65
D	8.38	8.69	9.65
D1	7.30	7.80	8.30
E	9.65	10.16	10.67
E1	8.00	8.62	9.00
e	5.08 BSC		
H	14.60	15.35	15.88
L	1.78	2.54	2.79
L1	0.90	1.29	1.68
L2	0.00	0.15	0.25
L3	0.25 BSC		
M	0°	4°	8°

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